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High-pressure phase transitions of nitinol NiTi to a semiconductor with an unusual topological structure

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1	High-Pressure Phase Transitions of Nitinol, NiTi, to a Semiconductor with Unusual
2	Topological Structure
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13	Abstract
14	Systematic ab-initio structure simulations have been used to explore the high-pressure behavior of nitinol
15	(NiTi) at zero temperature. Our crystal structure prediction and first principles calculations reveal that the known
16	B19 phase is dynamically unstable, an orthorhombic structure (Pbcm) and a face centered cubic B32 structure
17	(Fd-3m) become stable above ~4 and 29 GPa, respectively. The newly-predicted, highest-pressure, B32 phase is
18	composed of two interpenetrating diamond structures, with structural topology that is quite distinct from that of
19	the other phases of NiTi. Interestingly, the B32 phase shows unusual semiconducting characteristic as a result of
20	its unique band structure and the nature of $3d$ orbitals localization, whose expected synthesis pressure is
21	accessible to current experimental techniques.
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27	Key words: Nitinol, High Pressure, First Principles, Phase transition and Semiconductor.
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32 I. Introduction

33 Nickel titanium (NiTi), termed nitinol, is widely used in automotive, aerospace, electronics and mechanical 34 engineering as well as in medical devices. It is well-known for its shape memory and superelastic properties. Its 35 shape memory behavior is driven by a reversible martensitic phase transition from a high-temperature austenitic 36 B2 (*Pm*-3*m*) phase into a low-temperature martensitic phase [1,2] at around 273 K. Experimentally, single crystal 37 x-ray diffraction[3,4] and powder neutron diffraction measurements[5] have determined the low-temperature 38 phase as B19' $(P2_1/m)$ with $\gamma \sim 97.8^\circ$. Several experimental investigations have, however, reported the existence 39 of multiple coexisting phases.[6–8] A large number of computational studies have been performed to uncover the 40 underlying mechanism of phase transitions in NiTi.[9-16] Ab initio calculations revealed an additional 41 orthorhombic B19 (*Pmma*) phase as well as an 'R-phase' (P3), which are both low-symmetry distortions of the 42 high-symmetry B2 structure.[17] Density functional theory (DFT) calculations, in particular, have illuminated and 43 explained the controversies about the energy surface and properties of NiTi, and have suggested results which are 44 not always in agreement with the experimental observations. For example, the phonon frequencies of the 45 experimentally-observed ambient B2 phase were calculated to be imaginary in conventional *ab*-initial calculation, 46 indicating that this structure is dynamically unstable.[18] Moreover, the experimentally-observed low-temperature 47 B19' structure was predicted to be unstable with respect to a higher-symmetry base-centered orthorhombic (BCO) 48 B33 (*Cmcm*) structure at zero temperature [17], this B33 structure has not yet been confirmed in any experimental 49 study, furthermore this space group precludes this phase from being a shape memory martensite alloy derived 50 from the cubic structure. Many of these differences can be resolved if temperature-dependent entropic effects are 51 taken into account in the calculations. For example, a recent theoretical study has showed that B2 and B19' 52 structures are indeed stabilized, whereas the B33 structure is destabilized at finite temperature.[19]

53 Obviously, temperature factor plays a significant role in the martensitic structural phase transition of NiTi, leading to its shape memory effect, as underlined in both experimental and theoretical studies. But in addition to 54 55 temperature, pressure also plays a controlling role in inducing such transitions by altering the crystal and/or 56 electronic structures and generally pressure is well-recognized for creating novel structures and properties in 57 materials, including metals and alloys. For example, a pressure-induced metal-semiconductor transition in lithium 58 has been observed by direct electrical resistance measurements.[20] Transparent sodium was predicted by 59 computational work, and then experimentally observed at high pressure, associated with pressure-induced p-d 60 hybridization of valence electrons and their repulsion by core electrons into interstitial sites in the structure.[21] 61 Further examples of pressure-induced structural transitions include that from disordered structure to a long-range 62 face centered cubic (fcc) topological ordered structure in Ce₇₅Al₂₅, which was observed at 25 GPa[22]. The 63 ground-state phase of the prototype CoCrFeMnNi high-entropy alloy was retained during a high-pressure 64 irreversible phase transition under compression.[23] Nowadays, pressure has been recognized and deployed as a 65 very powerful and useful technique in the design, exploration and synthesis of novel functional materials. 66 Following this path, the high-pressure properties and phase diagram of NiTi has been investigated using 67 self-consistent *ab* initio lattice dynamical calculations which suggested that the B19' and B19 structures are stable 68 high-pressure phases.[24]

69 In this work, we employ crystal structure predictions and first principles total energy calculations based on 70 DFT, to further explore the high-pressure behavior of NiTi at zero temperature. Here, we find that the known B19 71 phase is dynamically unstable and report that the ground-state B33 phase transforms into a *Pbcm* phase at ~4 GPa, 72 and finally to a B32 (Fd-3m) phase at ~29 GPa. Actually, we find that the predicted *Pbcm* phase is a distorted 73 structure derived from the dynamically unstable B19 phase. The newly-uncovered B32 phase has a diamond-like 74 stacking sequence, whose topological crystal structure is completely different from any previously-reported 75 structural configuration of NiTi. The more intriguing prediction that the high-pressure B32 phase is a 76 semiconductor with a narrow direct bandgap of ~ 0.26 eV, is a consequence of the special band structure 77 associated with its unusual structural topology, which appears to be characterized by more localized 3d orbitals. 78 Our findings indicate that metallic NiTi alloy displays a rich family of abundant structural phase transitions and 79 will transform into an interestingly semiconducting state at high pressure, appears to show a new class of physical 80 and chemical mechanisms of transformation for a transition metal alloys.

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82 II. Computational details

83 The crystal structures of NiTi were probed systematically using the Crystal structure AnaLYsis by Particle 84 Swarm Optimization (CALYPSO) code[25,26], which is based on a search for the global minimum in the free 85 energy surfaces computed by the DFT total energy calculations. This method has been applied successfully to a wide range of crystalline systems ranging from elemental solids to binary and ternary compounds.[27-30] The 86 87 simulation cell comprised 1 to 8 formula units (2-16 atoms) of NiTi at 0, 10 and 40 GPa. The population size of 88 each generation was 50. The best 20 structures from last generation and 30 new ones generated by CALPYSO 89 algorithm composed the next generation. Generally, the search was terminated after the generation of 2000-2500 90 structures.

91 DFT calculations, including structural optimizations, enthalpies, electronic structures and phonons, were 92 performed using the Vienna Ab initio Simulation Package (VASP)[31] code employing the 93 Perdew-Burke-Ernzerhof[32] exchange-correlation functional. The $3d^84s^2$ and $3d^23s^2$ electrons were treated as valence electrons for Ni and Ti, respectively. Usually, the parameters of the structure searching are a little coarser than those of normal optimizations and enthalpy calculations to save CPU time, where energy cutoff is 400 eV and Monkhorst-Pack grid is $2\pi \times 0.05$ Å⁻¹ in reciprocal space here. We selected a lot of candidates (20-50) with low energy, then re-optimized all of them more precisely. To ensure that all enthalpy calculations were well converged, to about 1 meV/atom, a Monkhorst-Pack grid was selected with sufficient density ($2\pi \times 0.05$ Å⁻¹) in reciprocal space, as well as appropriate energy cutoff (450 eV).[33]

The phonon calculations and modulation of soft phonon mode were carried out using a finite displacement approach[34] through the PHONOPY code[35], which uses the Hellmann-Feynman forces calculated from the optimized supercells through VASP code. In our calculations of phonon spectra, we selected $2\pi \times 0.04$ Å⁻¹ and 700 eV as the parameters and extended the unit cells to be big enough supercells with volume larger than ~ 1000 Å³. For the B19 structure, the supercell is $3 \times 4 \times 3$, including 144 atoms; for the *Pbcm* structure, the supercell is $3 \times 4 \times 1$, including 96 atoms; and for the B32 structure, the supercell is $2 \times 2 \times 2$, including 128 atoms.

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107 III. Results and discussion

108 To validate our computational prediction method and DFT calculations in the NiTi system, using the 109 CALYPSO search, we successfully reproduced the known ambient B2 phase, low-temperature B19' phase and the 110 ground-state (0 K) B33 phase at atmospheric pressure, as well as their energy ordering: H(B2) > H(B19') >111 H(B33), verifying the reliability of our methodology. Then a new orthorhombic *Pbcm* phase and another cubic 112 B32 phase were found during structure searching at 10 and 40 GPa, respectively. The enthalpy of each phase as a 113 function of pressure is indicated in Figure 1. We find that the enthalpy of B33 phase is just a little lower than that 114 of the B19' phase, which is consistent with previous studies.[19] The B33 phase is stable up to \sim 4 GPa, then 115 transforms to the B19 phase or the *Pbcm* phase. It can be seen that it is very difficult to distinguish them on the 116 basis of their energy, because the energy difference between these two primitive orthorhombic structures is less 117 than the convergence accuracy of the energy calculation. At higher pressure (29 GPa), the B32 phase becomes 118 enthalpically favored.

In addition to the enthalpy calculations for these structures, we have also calculated their phonon dispersion curves. The dynamic stabilities of the B33 phase and B19' phase have been confirmed in theoretical study previously.[19] For the B19 phase, we found a soft phonon branch with negative frequencies running from the Γ -point (0, 0, 0) to the Z-point (0, 0, 0.5) to the T-point (-0.5, 0, 0.5) of the Brillouin Zone (BZ) indicating that this structure is dynamically unstable. (Figure 2a) We therefore modulated the structure by introducing atomic 124 displacements corresponding to the wavevector of the Z-point within a supercell of the B19 structure and we 125 obtained a *Pbcm* structure, which is the same structure as obtained in our crystal structure predictions. Actually, 126 the crystal structure of the predicted *Pbcm* phase is a distorted supercell of the known B19 phase. Over the entire 127 BZ, we found no imaginary phonon frequencies for this *Pbcm* phase nor for the B32 phase, confirming the 128 dynamic stability of each of these two structures. (Figure 2b and 2c) We also confirmed their mechanical 129 stabilities by computing the elastic constants.[33] Therefore, by considering both thermal and dynamical 130 stabilities, it appears safe to conclude that, at zero temperature, the *Pbcm* phase and the B32 phase are calculated 131 to be stable above ~ 4 and ~ 29 GPa, respectively.

132 In order to understand better the nature of the phase transitions between the high-pressure polymorphs of 133 NiTi, we consider the crystal structures and details of these phases, as shown in Figure 3 and Table I. Careful 134 observation of these NiTi crystal structures reveals that all of them, except the B32 phase, share the same 135 structural topology. They can all be derived from the highly symmetric simple cubic B2 structure. In these phases, 136 each Ti atom is eight-fold coordinated by Ni atoms and then regular or irregular hexahedra form their crystal 137 structures. Both the temperature-induced martensitic phase transition (B2 \rightarrow B19') and our newly-discovered 138 pressure-induced phase transition (B33 \rightarrow Pbcm) can be seen in terms of the varying relative displacements of Ni 139 and Ti atoms, derived from a (seriously) distorted B2 structure.

140 In contrast, the high-pressure B32 structure shows a completely different topological crystal structure, and 141 can be viewed as two interpenetrating diamond structures separated by a vector of (0.5, 0.5, 0.5). Each Ti atom is 142 tetrahedrally coordinated by four Ti atoms and by four Ni atoms at identical distances, thus forming a 143 superstructure of the body centered cubic (bcc) lattice, which often occurs in certain intermetallic I-III compounds 144 (LiAl, LiGa, NaTl) and I-IIB alloys (LiZn, LiCd).[36] Thus, it can be seen that the transformation to the B32 145 phase involves a significant topological rearrangement and is a reconstructive phase transition, in contrast with the 146 others structural phase transitions in NiTi. Therefore, the energy barrier of reconstructive phase transition (*Pbcm*) 147 \rightarrow B32) is expected to be significantly higher than that of the lower-pressure transition (B33 \rightarrow Pbcm). 148 Additionally, we have calculated the equation of states of all these NiTi structures.[33] We find that the B32 phase 149 is significantly denser than the other phases due to the nature change from (distorted) bcc stacking to close-packed 150 fcc one, further underlining the expectation that this phase becomes most stable at extreme pressure.

To further investigate the electronic properties of NiTi, the band structures and the density of states (DOS) of all phases were studied by first principles calculations. It is expected that the B2, B33, and *Pbcm* phases show metallic behavior, as in a typical alloy system, where the valence bands and conduction bands completely overlap 154 and the DOS at the Fermi level is very high.[33] However, our computational results indicate that the predicted 155 B32 structure shows a bandgap. It is well known that DFT usually underestimates the bandgap of materials, and 156 we thus employed the screened hybrid functional of Heyd, Scuseria, and Ernzerhof (HSE06)[37] to better 157 determine the electronic properties of this structure. The modified band structure (Figure 4) clearly shows that the 158 B32 phase shows semiconducting character with a direct bandgap of ~0.26 eV between the Γ and X points, which 159 is consistent with its DOS. From the projected DOS, we find that most of the electronic states below the Fermi 160 level are associated with Ni 3d electrons, but also partly by Ti 3d electrons and their s, p orbitals. In contrast, the 161 conduction band is composed of mainly by Ti 3d electrons.

162 Here, the novel electronic properties of B32 phase may directly contribute to nature of it crystal structure, a 163 Zintl phase. Usually, such structures are poor conductors or semiconductors. Normally, such phases are the 164 products of a reaction between group I/II elements and any post-transition metal or metalloid. The classic Zintl 165 phase, NaTl, displays complete electron transfer from the more electropositive Na to the more electronegative Tl, 166 just as in genuine ionic salts such as NaCl.[38] It behaves likes a group IV element, and it forms a diamond 167 network structure. Thus, the band structure and density of states have characteristics related to those of the 168 tetrahedrally bonded IV-IV semiconductors. For example, a study of LiAl indicates that while the Li-Al bond is an 169 ionically polarized covalent bond, the Al-Al bonds are metallic-like and the Li-Li interactions are essentially 170 nonbonding. It was found that this system shows a semimetallic band structure.[39] Our Bader population 171 analysis [40] reveals an electron transfer of $\sim 0.88 e$ from Ti to Ni in the B32 phase. In this B32 phase Ti and Ni 172 show, to first approximation, +1 and -1 valence states, respectively, akin to LiAl, and the B32 structure of NiTi 173 shows an obvious bandgap-

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175 IV. Conclusions

176 In summary, we performed systematically theoretical studies on the structural variability and associated 177 physical properties of NiTi alloy at high pressures. Through structure prediction method and first principles 178 calculations, at zero temperature, we identify that its ground-state B33 phase transforms into a predicted 179 higher-pressure Pbcm phase, and then to a highly symmetric B32 phase under increased compression. Further 180 DFT studies reveal that the newly-uncovered B32 phase of this NiTi alloy shows an interestingly semiconducting 181 behavior, which is associated with its special topological phase transition and the characteristic of 3d electrons. 182 The present study provides new insights into the exploration and design of distinctive alloy materials under 183 extreme condition.

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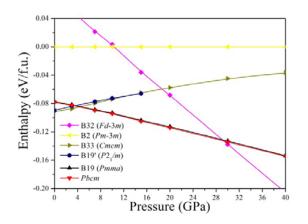
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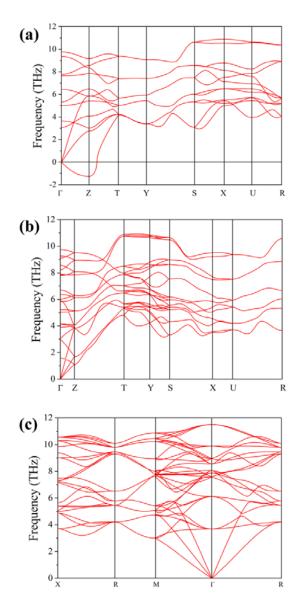
194 Table I. The calculated crystal structure information of NiTi at different pressures.

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Space group	Pressure (GPa)	Lattice parameters (Å)	Atoms	x	У	Ζ
D 2 (D2)	0	<i>a</i> = 3.003	Ti	0.5	0.5	0.5
<i>Pm</i> -3 <i>m</i> (B2)			Ni	0	0	0
	0	<i>a</i> = 4.687				
\mathbf{p} (D102)		<i>b</i> = 4.038	Ti	0.2189	0.25	0.0127
<i>P</i> 2 ₁ / <i>m</i> (B19')		<i>c</i> = 2.930	Ni	0.6746	0.25	0.0491
		$\beta = 98.97^{\circ}$				
Cmcm	0	<i>a</i> = 2.888	Ti	0	0.1440	0.75
(B33/BCO)		<i>b</i> = 9.398	Ni	0	0.5847	0.75
(633/600)		<i>c</i> = 4.042	INI	0	0.3647	0.23
	20	<i>a</i> = 4.176	Ti	0.25	0	0.2923
<i>Pmma</i> (B19)		<i>b</i> = 2.578			÷	
		<i>c</i> = 4.505	Ni	0.25	0.5	0.8172
	20	<i>a</i> = 2.572	Ti	0.0528	0.3975	0.25
Pbcm		<i>b</i> = 9.029				
		<i>c</i> = 4.176	Ni	0.5357	0.1598	0.25
Ed 2m (D22)	40	<i>a</i> =5.585	Ti	0.5	0.5	0
<i>Fd</i> -3 <i>m</i> (B32)	40	u -3.383	Ni	0	0	0.5



- 198 Figure 1: The calculated enthalpy as a function of pressure for each NiTi structure.
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201 Figure 2: The phonon dispersions of NiTi in its (a) B19 structure at 20 GPa, (b) *Pbcm* structure at 20 GPa, (c) B32

structure at 40 GPa.

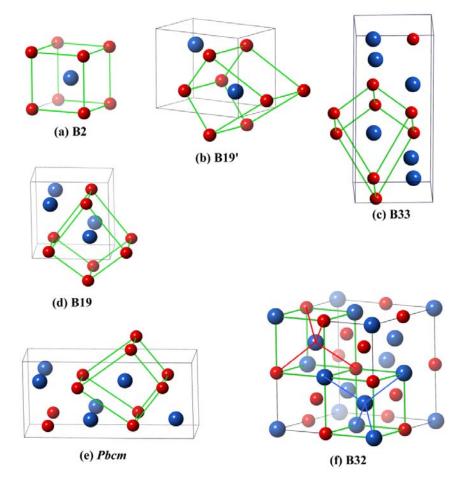


Figure 3: The schematic crystal structures of the NiTi phases (a) B2, (b) B19', (c) B33, (d) B19, (e) *Pbcm* and (f)

206 B32. Large blue and small red spheres represent Ni and Ti atoms, respectively.

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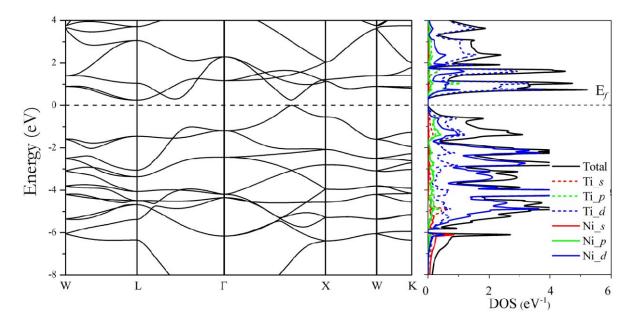


Figure 4: Band structure along high symmetry path and the projected DOS of the B32 structure at 40 GPa. The

210 Fermi level has been set to 0 eV.

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